

isc Silicon PNP Power Transistor

2SA1185

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= -50V(Min.)
- · Low Collector-Emitter Saturation Voltage-
 - : V_{CE(sat)}= -0.8V(Max.)@ I_C= -7A
- · Good Linearity of hFE
- Large Collector Current
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

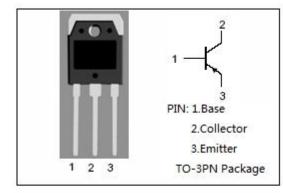


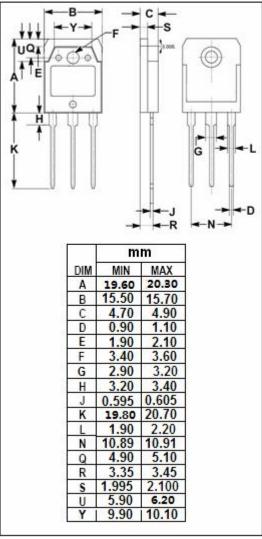
APPLICATIONS

Designed for high power audio frequency amplifier applications



SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	-50	V	
V_{CEO}	Collector-Emitter Voltage	-50	V	
V_{EBO}	Emitter-Base Voltage	-5	V	
Ic	Collector Current-Continuous	-7	А	
Ісм	Collector Current-Peak	-15	А	
Івм	Base Current-Peak -5		А	
Pc	Collector Power Dissipation @ T _C =25 °C	60	W	
	Collector Power Dissipation @ T _a =25°C	2.5		
TJ	Junction Temperature	ion Temperature 150 °C		
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	







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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -10mA ; I _B = 0	-50			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -7A; I _B = -0.7A			-0.8	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -7A; V _{CE} = -5V			-1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -50V; I _E = 0			-1	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-2	mA
h _{FE-1}	DC Current Gain	I _C = -1A; V _{CE} = -5V	60		320	
h _{FE-2}	DC Current Gain	I _C = -7A; V _{CE} = -5V	20			
Сов	Collector Output Capacitance	I _E = 0; V _{CB} = -10V; f= 1MHz		250		pF
f⊤	Current-Gain—Bandwidth Product	I _C = -0.5A; V _{CE} = -5V		100		MHz

h_{FE-1} Classifications

Q	Р	0
60-120	100-200	160-320

NOTICE:

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